SAMYANG ELECTRONICS

1N4933---1N4937

FAST RECOVERY RECTIFIER

VOLTAGE RANGE: 50 --- 600 V
CURRENT: 1.0 A

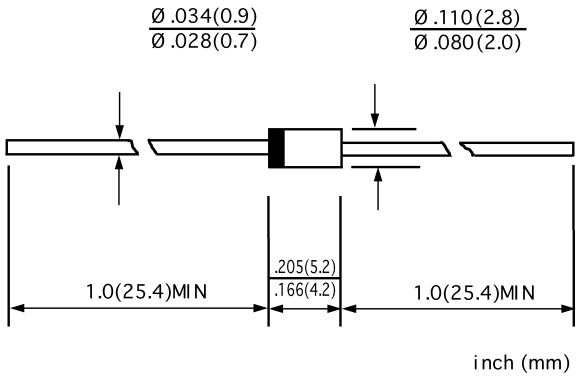
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon,Alcohol,Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case:JEDEC DO-41,molded plastic
- ◇ Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.34 grams
- ◇ Mounting position: Any

DO - 41



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		1N 4933	1N 4934	1N 4935	1N 4936	1N 4937	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	V
Maximum average forw ard rectified current 9.5mm lead length, @T_A=75℃	$I_{F(AV)}$	1.0					A
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load @T_J=125℃	I_{FSM}	30.0					A
Maximum instantaneous forw ard voltage @ 1.0 A	V_F	1.3					V
Maximum reverse current @T_A=25℃	I_R	5.0					μA
at rated DC blocking voltage @T_A=100℃		100.0					
Maximum reverse recovery time (Note1)	t_{rr}	200					ns
Typical junction capacitance (Note2)	C_J	12					pF
Typical thermal resistance (Note3)	R_{JA}	55					℃
Operating junction temperature range	T_J	- 55---- +150					℃
Storage temperature range	T_{STG}	- 55---- + 150					℃

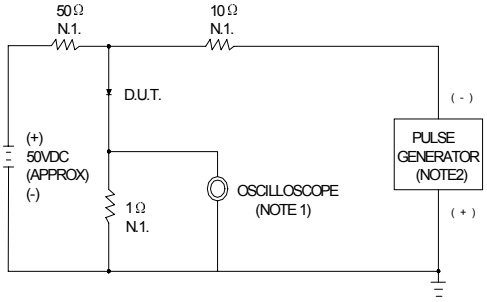
NOTE:1. Measured with I_F=0.5A, I_R=1A, I_{rr}=0.25A.

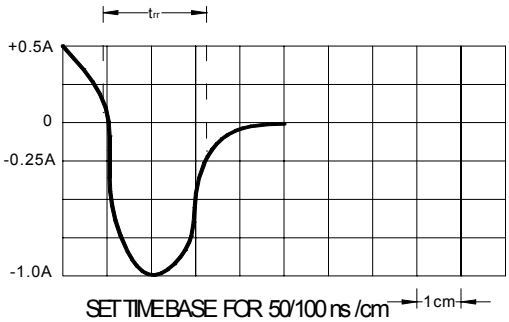
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM





NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ. 22PF
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω

FIG.2 –FORWARD DERATING CURVE

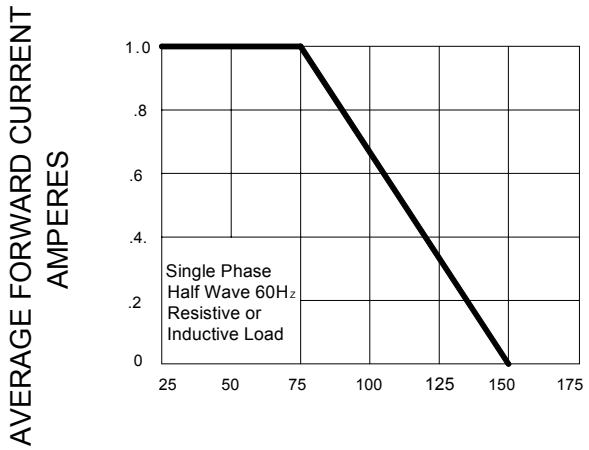


FIG.3 – TYPICAL FORWARD CHARACTERISTICS

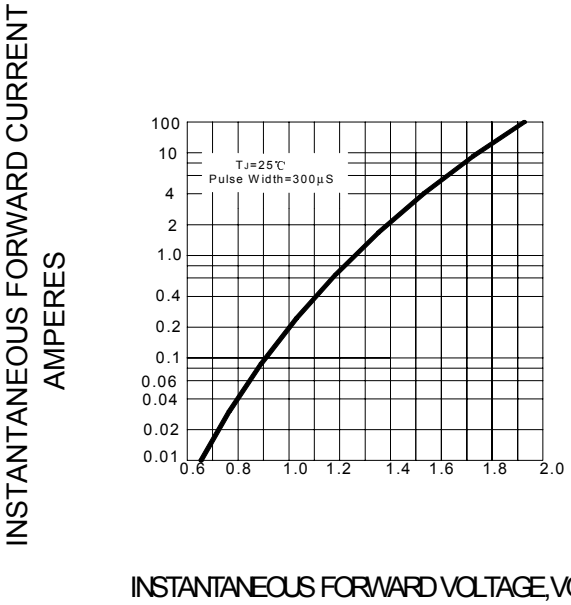


FIG.4–PEAK FORWARD SURGE CURRENT

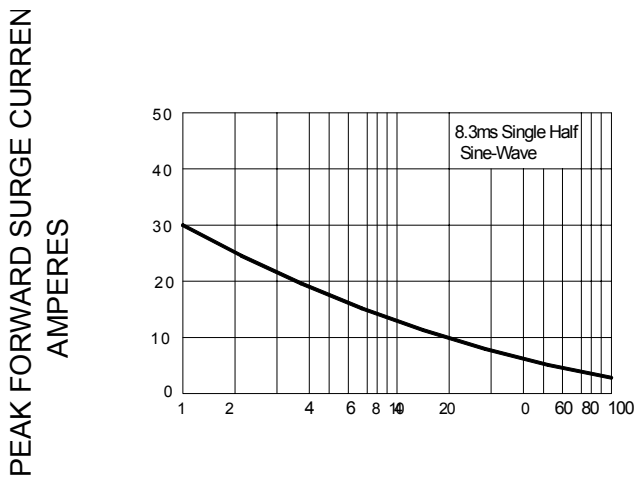


FIG.5– TYPICAL JUNCTION CAPACITANCE

